

PATENT NUMBER

U.S. UTILITY Patent Application

JL2
JC858

O.I.P.E.

PATENT DATE

SCANNED

Q.A

APPLICATION NO.
09/662682

CONT/PRIOR

CLASS
438

SUBCLASS
115

ART UNIT
1765

EXAMINER

Vinh


ICANTS Xiuling Li
Paul Bohn
Jonathan Sweedler

Metal-assisted chemical etch porous silicon formation method

PTO-2040
12/89

ISSUING CLASSIFICATION

ORIGINAL				CROSS REFERENCE(S)							
CLASS		SUBCLASS		CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)						
INTERNATIONAL CLASSIFICATION											
						</					

 TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	_____ (Assistant Examiner) _____ (Date)			NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. _____	_____ (Primary Examiner) _____ (Date)			ISSUE FEE	
				Amount Due	Date Paid
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	_____ (Legal Instruments Examiner) _____ (Date)			ISSUE BATCH NUMBER	
WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368. Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.					

Form PTO-436A
(Rev. 6/99)

FILED WITH: ☒ DISK (CRF) ☐ FICHE ☐ CD-ROM
(Attached in pocket on right inside flap)

BEST AVAILABLE COPY

(FACE)